

CNZ3731, CNC7C501, CNZ3734, CNC2S501, CNC7C502, CNC7H501 (ON3731, ON3732, ON3734, ON3731A, ON3732A, ON3734A)

Optoisolators

Overview

The CNZ3731 series of optoisolators consist of a GaAs infrared LED which is optically coupled with a Si NPN Darlington phototransistor, and housed in a small DIL package. The series provides high I/O isolation voltage and high collector/emitter isolation voltage, as well as a high current transfer ratio (CTR). This opto isolator series also includes the two-channel CNC7C501 and the four-channel CNZ3734, and A type of these models with increased collector to emitter breakdown voltage ($V_{CEO} > 350V$).

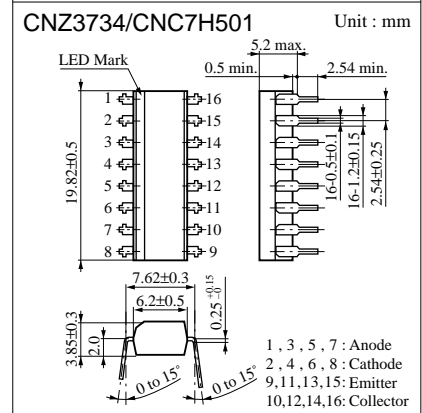
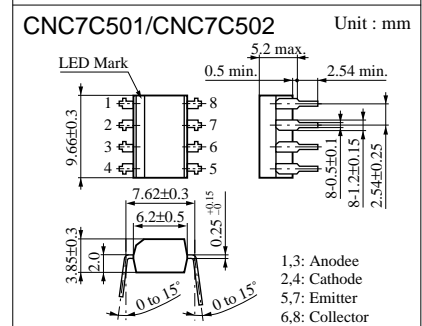
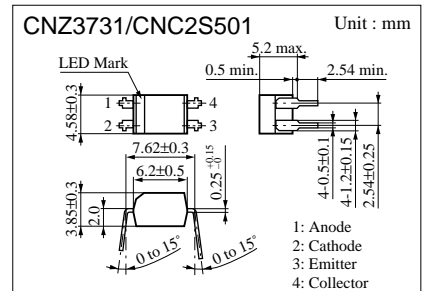
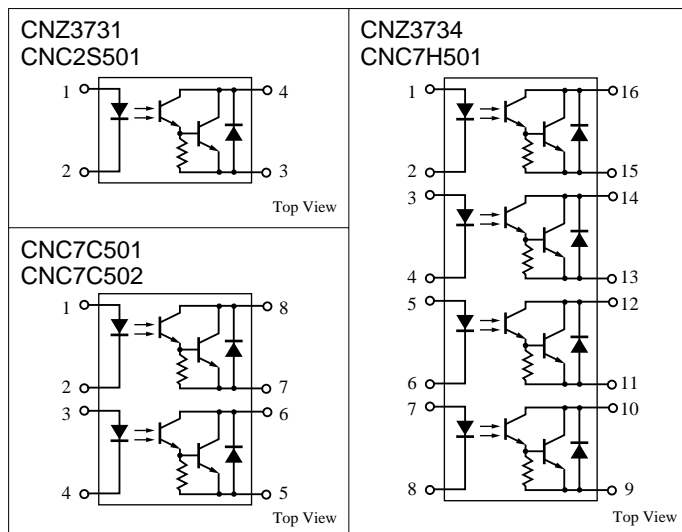
Features

- High collector to emitter breakdown voltage : $V_{CEO} > 300 V$,
A type : $V_{CEO} > 350 V$
- High current transfer ratio with Darlington phototransistor output :
CTR = 4000% (typ.)
- High I/O isolation voltage : $V_{ISO} \geq 5000 V_{rms}$
- Small DIL package for saving mounting space
- UL listed (UL File No. E79920)
- A-type models have a guaranteed internal insulating distance of 0.4 mm

Applications

- Telephones
- Telephone exchange
- FAX
- Programmable controllers
- Signal transfer between circuits with different potentials and impedances

Pin Connection



Note) The part numbers in the parenthesis show conventional part number.

Absolute Maximum Ratings (Ta = 25°C)

Parameter		Symbol	Ratings				Unit
			CNZ3731	CNC7C501 CNZ3734	CNC2S501	CNC7C502 CNC7H501	
Input (Light emitting diode)	Reverse voltage (DC)	V_R	6		6		V
	Forward current (DC)	I_F	50		50		mA
	Pulse forward current	I_{FP}^{*1}	1		1		A
	Power dissipation	P_D^{*2}	75		75		mW
Output (Photo transistor)	Collector current	I_C	150		150		mA
	Collector to emitter voltage	V_{CEO}	300		350		V
	Emitter to collector voltage	V_{ECO}	0.3		0.3		V
	Collector power dissipation	P_C^{*3}	300	150	300	150	mW
Total power dissipation		P_T	320	200	320	200	mW
Isolation voltage, input to output		V_{ISO}^{*4}	5000		5000		V_{rms}
Operating ambient temperature		T_{opr}	-30 to +100		-30 to +100		°C
Storage temperature		T_{stg}	-55 to +125		-55 to +125		°C

*1 Pulse width $\leq 100 \mu s$, repeat 100 pps

*2 Input power derating ratio is 0.75 mW/°C at $T_a \geq 25^\circ C$.

*3 Output power derating ratio is 3.0 mW/°C at $T_a \geq 25^\circ C$ (CNZ3731, CNC2S501).

Output power derating ratio is 0.75 mW/°C at $T_a \geq 25^\circ C$ (CNC7C501, CNC2S502, CNZ3734, CNC7H501).

*4 AC 1min., RH < 60 %

Electrical Characteristics (Ta = 25°C)

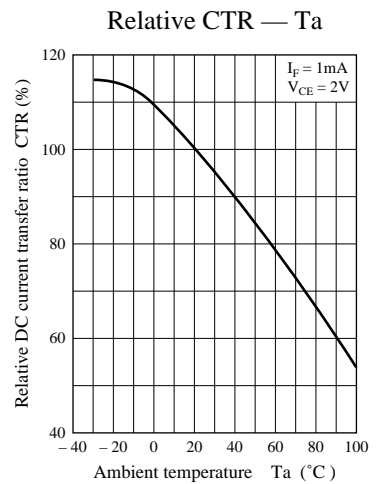
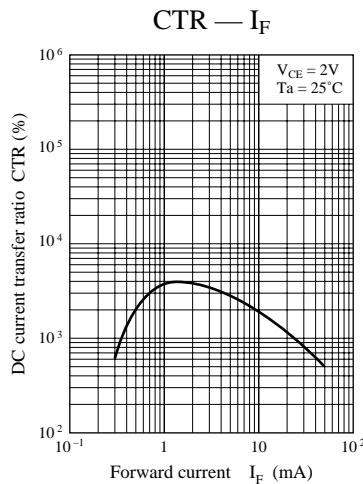
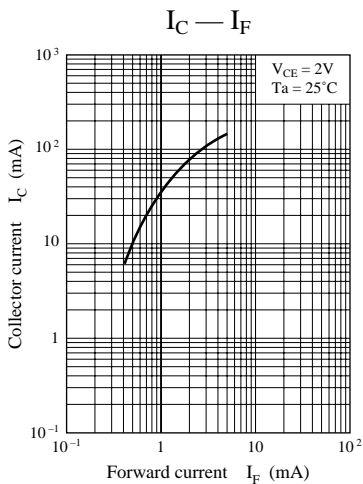
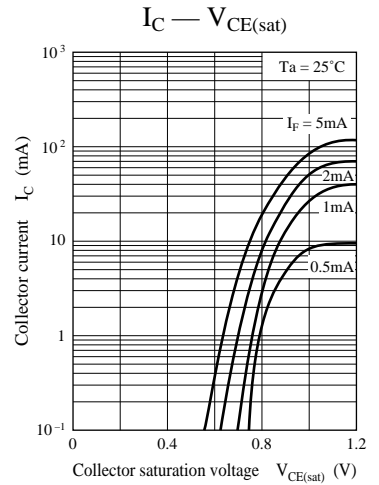
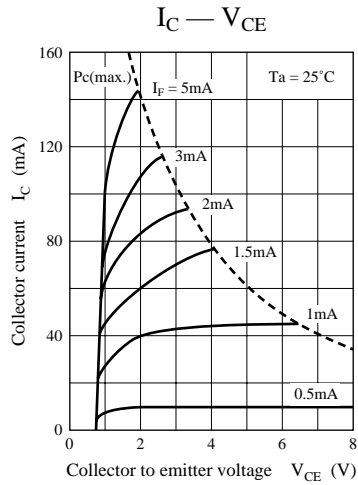
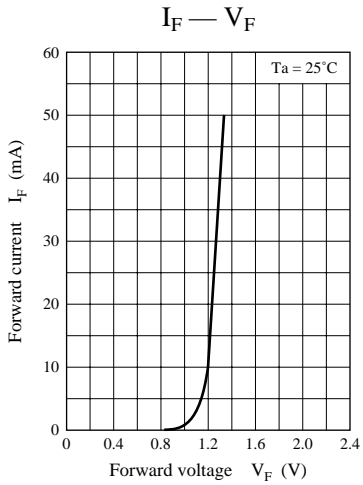
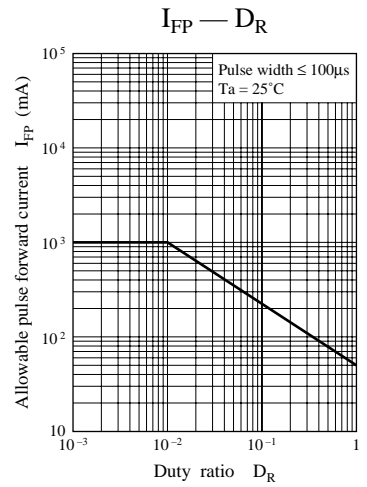
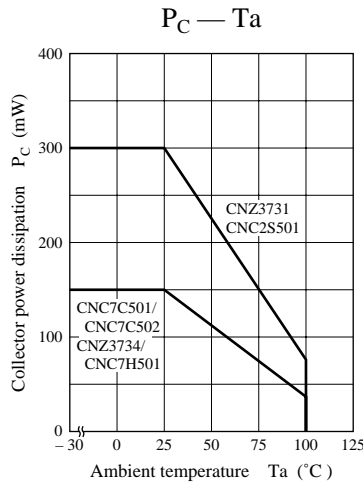
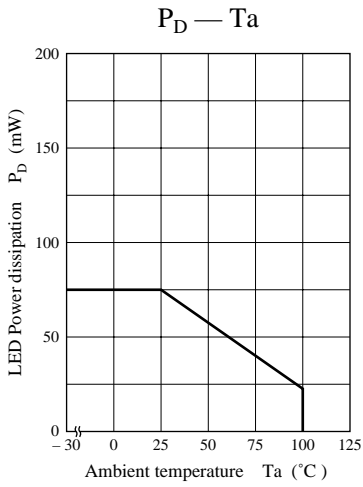
Parameter		Symbol	Conditions	min	typ	max	Unit
Input characteristics	Reverse current (DC)	I_R	$V_R = 3V$			10	μA
	Forward voltage (DC)	V_F	$I_F = 50mA$		1.35	1.5	V
	Capacitance between pins	C_t	$V_R = 0V, f = 1MHz$		30		pF
Output characteristics	Collector cutoff current	I_{CEO}	$V_{CE} = 200V$			200	nA
	Collector to emitter capacitance	C_C	$V_{CE} = 10V, f = 1MHz$		10		pF
Transfer characteristics	DC current transfer ratio	CTR ^{*1}	$V_{CE} = 2V, I_F = 1mA$	1000	4000		%
	Isolation capacitance, input to output	C_{ISO}	$f = 1MHz$		0.7		pF
	Isolation resistance, input to output	R_{ISO}	$V_{ISO} = 500V$	10^{11}			Ω
	Rise time	t_r^{*2}	$V_{CC} = 10V, I_C = 10mA,$		40		μs
	Fall time	t_f^{*3}	$R_t = 100\Omega$		15		μs
Collector to emitter saturation voltage		$V_{CE(sat)}$	$I_F = 1mA, I_C = 2mA$			1.0	V

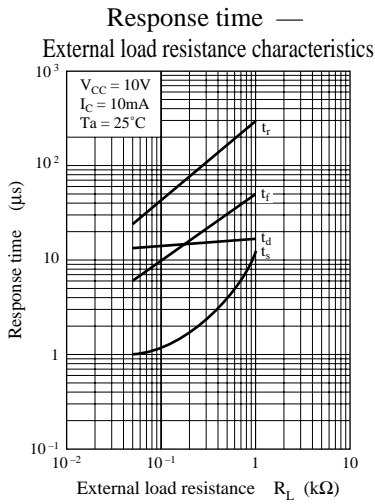
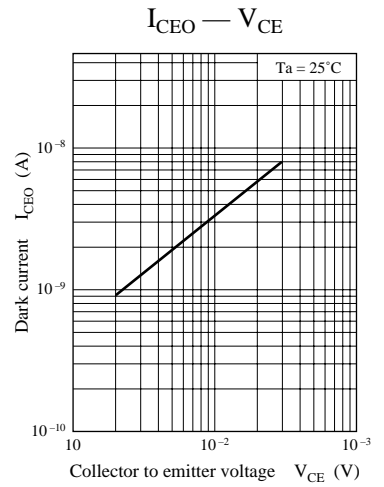
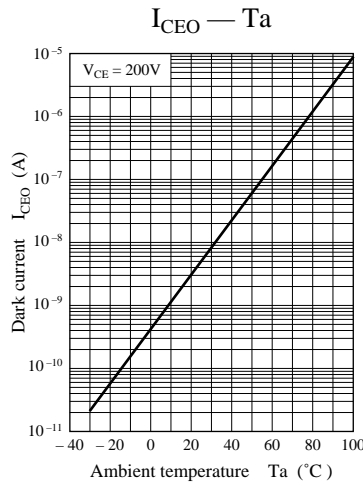
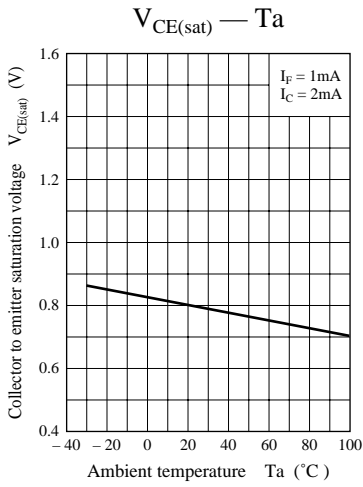
*1 DC current transfer ratio (CTR) is a ratio of output current against DC input current.

$$CTR = \frac{I_C}{I_F} \times 100 (\%)$$

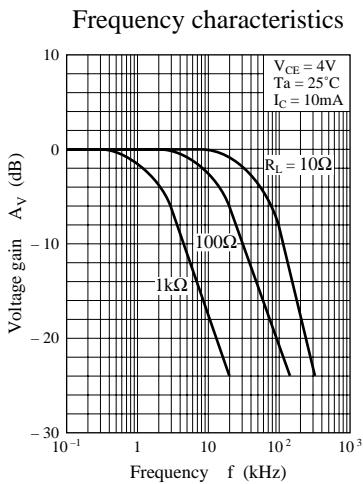
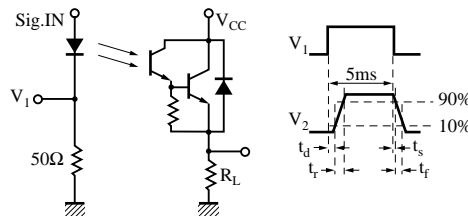
*2 t_r : Time required for the collector current to increase from 10% to 90% of its final value

*3 t_f : Time required for the collector current to decrease from 90% to 10% of its initial value

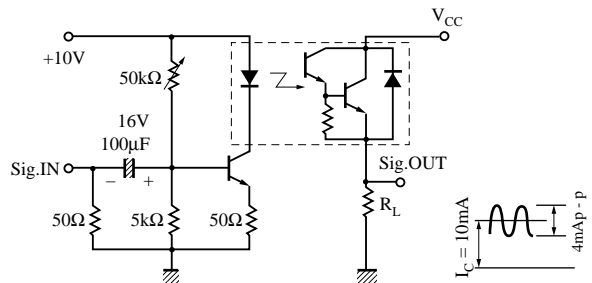




Response time measurement circuit



Measurement circuit of frequency characteristics



Caution for Safety

 **DANGER**

Gallium arsenide material (GaAs) is used in this product.

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